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**CORRIGENDUM:** Large Linear Magnetoresistance and Shubnikov-de Hass Oscillations in Single Crystals of YPdBi Heusler Topological Insulators

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This Article contains errors in the inset of Figure 1c: the atoms are mislabelled in the half-Heusler structure. The correct Figure 1 appears below. Yellow spheres at (0, 0, 0) are Y atoms, green spheres at (0.75, 0.75,0.75) are Pd atoms, and purple spheres at (0.5,0.5,0.5) are Bi atoms.

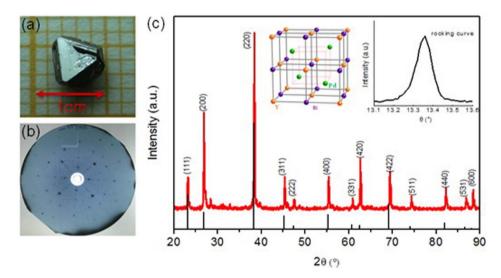


Figure 1